

T496B106K016BH6110

T496 HRA, Tantalum, MnO₂ Tantalum, HRA, 10 uF, 10%, 16 VDC, SMD, MnO₂, Molded, Military, Fused, High Reliability, B (0.1%/1000 Hrs), 3.5 Ohms, 3528, 2.1 mm, 0.8 mm

CATHODE (-) END VIEW



SIDE VIEW



ANODE (+) END VIEW



BOTTOM VIEW



Click [here](#) for the 3D model.

General Information

Series	T496 HRA
Dielectric	MnO ₂ Tantalum
Style	SMD Chip
Description	SMD, MnO ₂ , Molded, Military, Fused, High Reliability
Features	Internal Fuse, High Reliability
RoHS	No
Prop 65	WARNING: Cancer and reproductive harm - https://www.p65warnings.ca.gov/
SCIP Number	1dd2e1b8-26dd-4d52-927c-6f9d519011aa
Termination	Tin Lead (SnPb)
AEC-Q200	No
Typical Component Weight	107.45 mg

Dimensions

L	3.5mm +/-0.2mm
W	2.8mm +/-0.2mm
H	1.9mm +/-0.2mm
T	0.13mm REF
S	0.8mm +/-0.3mm
F	2.2mm +/-0.1mm
A	1.9mm MIN
B	0.4mm +/-0.15mm
E	2.2mm REF
G	1.8mm REF
P	0.4mm REF
R	1.5mm REF
X	0.1mm +/-0.1mm REF

Packaging Specifications

Packaging	T&R, 178mm
Packaging Quantity	2000

Specifications

Capacitance	10 uF
Tolerance	10%
Voltage DC	16 VDC (85C), 10.72 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
Dissipation Factor	6% 120Hz 25C
Failure Rate	B (0.1%/1000 Hrs)
ESR	3500 mOhms (100kHz 25C)
Ripple Current	156 mA (rms, 100kHz 25C)
Leakage Current	1.6 uA (5min 25°C)
Testing and Reliability	Standard Testing Only

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